

Author Correction: Robust memristors based on layered two-dimensional materials

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In the version of this Article originally published, the author Xiaoqing Pan's two affiliations with the University of California, Irvine, were mistakenly omitted. They are: Department of Chemical Engineering and Materials Science, University of California, Irvine, CA, USA; Department of Physics and Astronomy, University of California, Irvine, CA, USA. These have now been included in the Article.

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